SP6025E
Dual LLC Synchronous Rectifier

DESCRIPTION

The fundamental of SP6025E synchronous rectifier (SR) driver IC combines our U.S. patented methods that utilize the principle of “prediction” logic circuit and current mode. The IC deliberates previous cycle timing to linear control the SR in present cycle by “predictive” algorithm that makes adjustments to the turn-off time, in order to achieve maximum efficiency and avoid cross-conduction at the same time. Specially, SP6025E is designed for LLC applications, and variable switching frequency system.

The SP6025E is a dual, fast turn-off intelligent controller to drive two N-MOSFETs in LLC resonant converters for synchronous rectification.

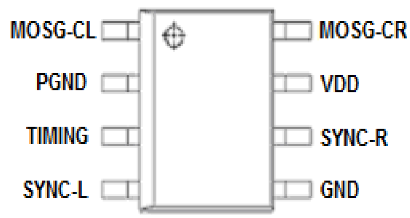
APPLICATIONS

- Storage area network power supplies
- PC power supply
- Embedded systems
- Industrial & commercial systems using high current processors

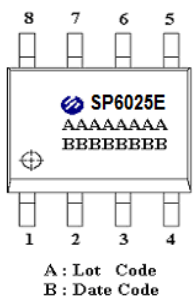
FEATURES

- Offers efficiency improvement over Schottky Diode.
- Low standby power to meet DOE Lot 6 requirement
- Dual gate driver
- Wide supply voltage range from 4.5V to 35V
- Self-detect DCM/CCM operation to enhance performance under variable switching frequency operation
- Current mode operation in DCM, Prediction mode control in CCM
- Rapid tracking function in prediction mode to adapt rapid load changing
- Multi-blanking time to avoid the interference of the turn on noise
- Available in SOP-8 package

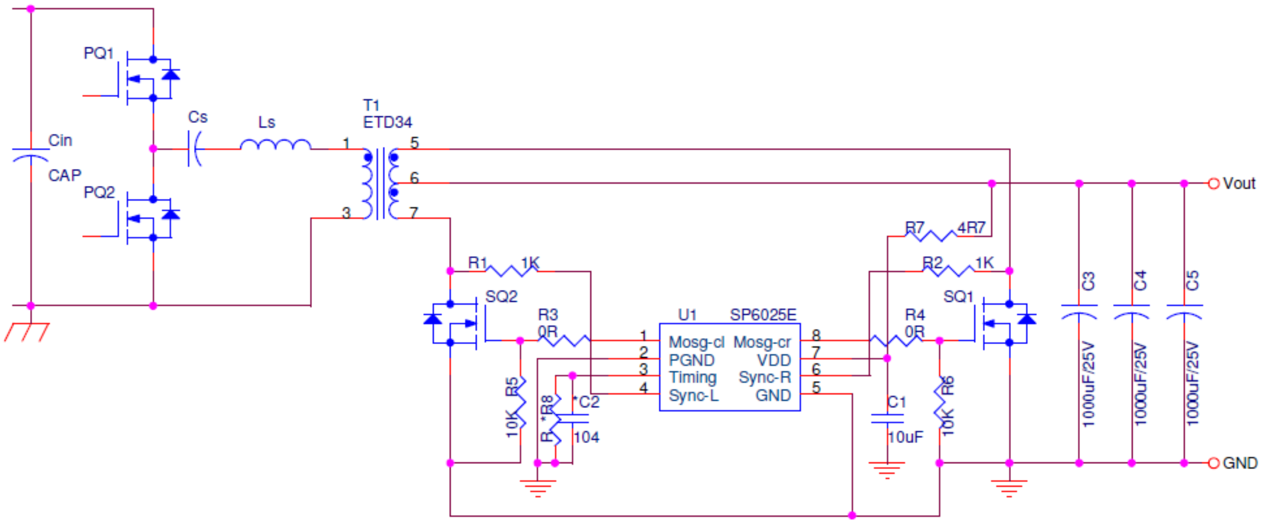
PIN CONFIGURATION (SOP-8)



PART MARKING



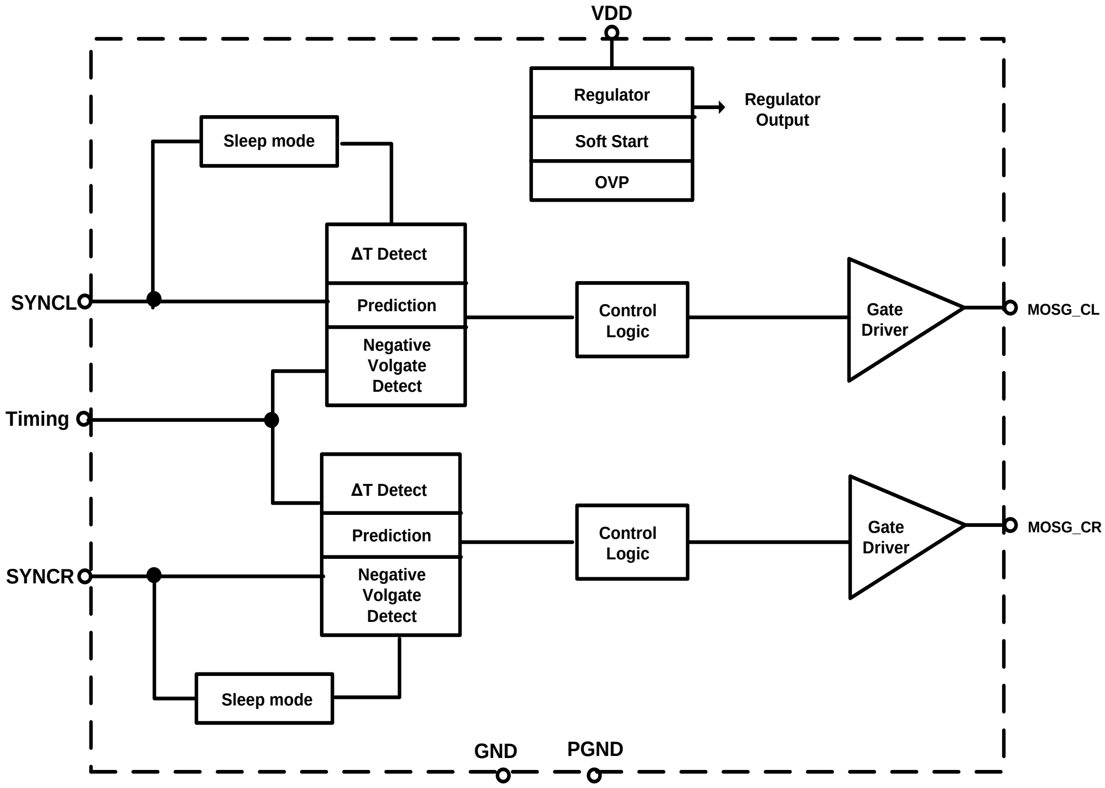
TYPICAL APPLCATION CIRCUIT



PIN DESCRIPTION

Pin	Symbol	Description
1	MOSG_CL	MOSFET_L gate driver.
2	PGND	Power ground connection.
3	TIMING	Discontinuous current filter timing adjustment resistor.
4	SYNC_L	Synchronized signal from the V_{DS} of SR MOSFET.
5	GND	Source pin ground connection.
6	SYNC_R	Synchronized signal from the V_{DS} of SR MOSFET.
7	VDD	DC supply voltage.
8	MOSG_CR	MOSFET_R gate driver.

BLOCK DIAGRAM



ORDERING INFORMATION

Part Number	Package	Part Marking
SP6025ES8RGB	SOP-8	SP6025E

※ SP6025ES8RGB : Tape Reel; Pb – Free; Halogen - Free

ABSOULTE MAXIMUM RATINGS (T_A=25℃, unless otherwise specified.)

The following ratings designate persistent limits beyond which damage to the device may occur.

Symbol	Paramete	Value	Unit
V_{DD}	DC Supply voltage	-0.3~40	V
SYNC-R/L	Sync input pin voltage	-1~200	V
MOSG-R/L	Output pin voltage	-0.3~12	V
TIMING	In/Out pin voltage	-0.3~5.5	V
I_{OUT}	Peak Source Current (Pulsed)	0.35	A
P_D	Power Dissipation @ T_A=25℃	1.1	W
T_J	Operating Junction Temperature Range	-40 to150	℃
T_{STG}	Storage Temperature Range	-40 to 150	℃
T_{LEAD}	Lead Soldering Temperature for 5 sec.	260	℃

THERMAL RESISTANCE

Symbol	Paramete	Value	Unit
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (1)	114	℃/W
$R_{\theta JC}$	Thermal Resistance Junction to Case (1)	45	℃/W

(1)The power dissipation and thermal resistance are evaluated under copper board mounted with free air conditions

ELECTRICAL CHARACTERISTICS

(T_A=25℃, V_{DD}=24V, Freq. =50 KHz, Duty Cycle=50%, unless otherwise specified.)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
SUPPLY INPUT						
I_{DD}	Supply current	No load	2	3	4	mA
		V_{SYNC}=V_{DD}, (Sleep mode)	0.15	0.28	0.45	mA
I_{DD} Clamp	Clamp current	V_{DD}=37V		1.5		mA
		V_{DD}=38.5V		6	10	mA
V_{DD} on	Enable voltage		3.1	3.45	3.8	V
V_{DD} hysteresis	Enable voltage		0.1	0.3	0.5	V
V_{OVP}	Over voltage protection		33	35	37	V
V_{OVP} hysteresis			1	3	5	V
SYNC REFERENCE (SYNC)						
V_{SYNC_on}	Turn-on threshold		-150	-250		mV
V_{Gate_low}	Gate pull low threshold			-35		mV
V_{SYNC_off}	Turn-off threshold			20		mV
I_{SYNC}	Sync input current	Isync happens at V_{DS} < 5V			10	mA
CONTROL CIRCUIT SECTION						
TDon	Turn-on delay	C_{LOAD}=4.7nF,V_{GS}=2V		145	165	nS
TDoff	Turn-off total delay	V_{SYNC}=0V,C_{LOAD}=4.7nF, R_{GATE}=0Ω, V_{GS}=2V		40	65	nS
TBon	Turn-on total blanking time			1		uS
VBoff	Turn-off blanking V_{DS} threshold			1.8		V
Ttiming	Falling slope detection timer Vsync from 1.8V to -50mV	Rtiming=100KΩ		130		nS
Vtiming	Reference Voltage	Rtiming=100KΩ	1.155	1.195	1.23	V
T_{LL1}	Light-load-enter pulse width	SR MOS V_{DS} pulse width<T_{LL1}		1		uS
T_{LL-DEL}	Light-load-enter delay	Continuous counting cycles		8		cycle
T_{LL2}	Light-load-enter pause width	SR MOS V_{DS} pulse width>T_{LL2}		35		uS
Tpred	Prediction time	Fixed setting		175	300	nS
MOSFET GATE DRIVER(MOSG-C)						
Vout_Pred	Output clamp voltage in Prediction mode	Trising < Tset of rising		9.5		V
Vout_Current	Output clamp voltage in Current mode	Trising > Tset of rising		8		V
Tr	Rise time	Load=4.7nF(2)		250		nS
Tf	Fall time	Load=4.7nF(2)		15		nS
	Pull up impedance	Peak current		14		Ω
	Pull down impedance			0.8		Ω

Notes:
(2) Guaranteed by design and characterization

PERFORMANCE CHARACTERISTICS (T_A=25℃, unless otherwise specified.)

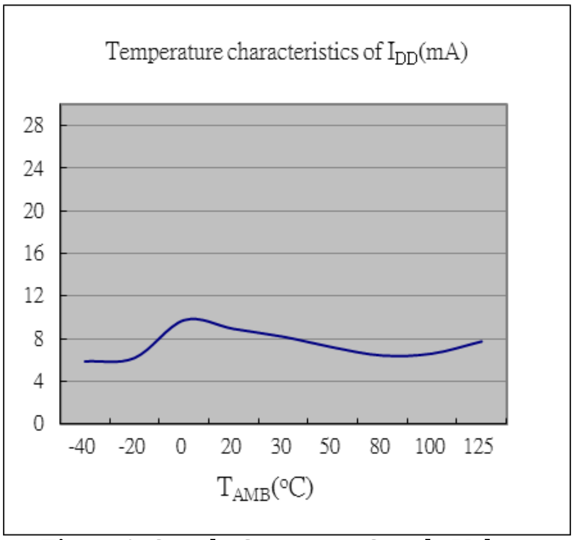


Figure 1: Supply Current vs Supply Voltage

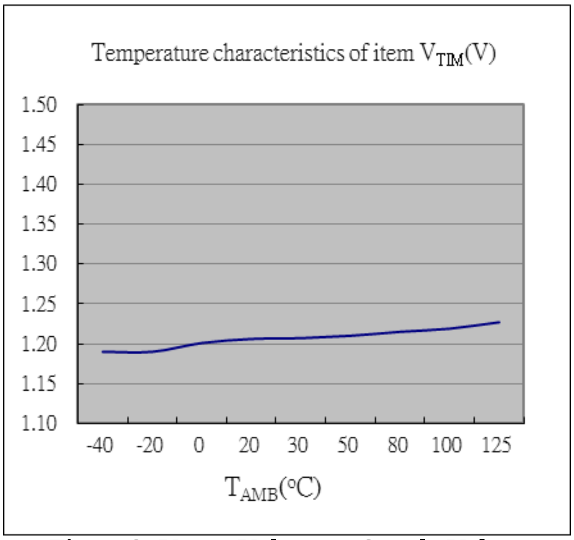


Figure 2: V_{Timing} Voltage vs Supply Voltage

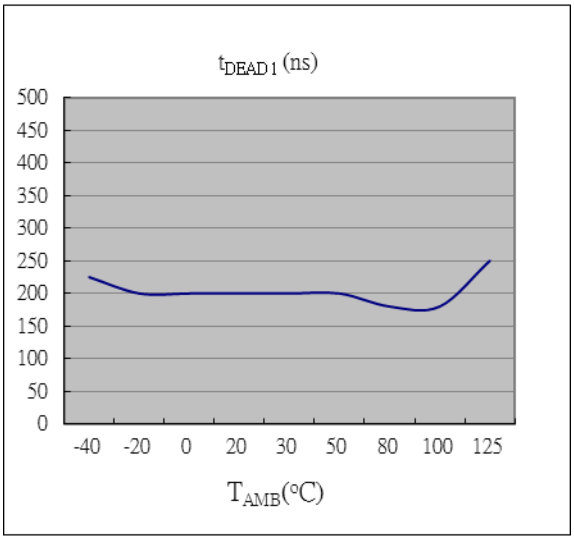


Figure 3: $t_{DEAD\ 1}$vs Temperature (℃)

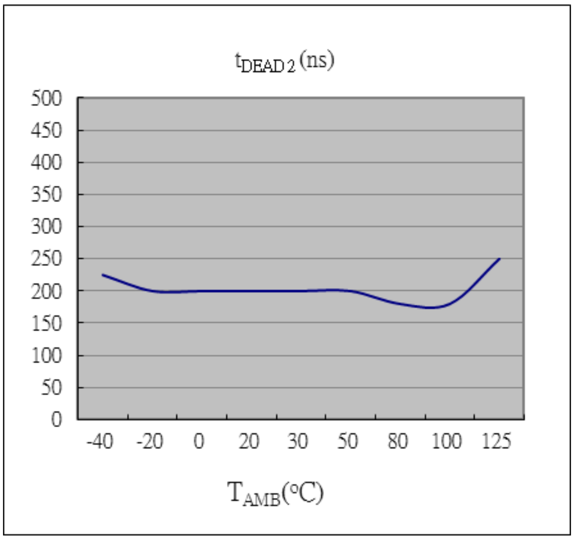
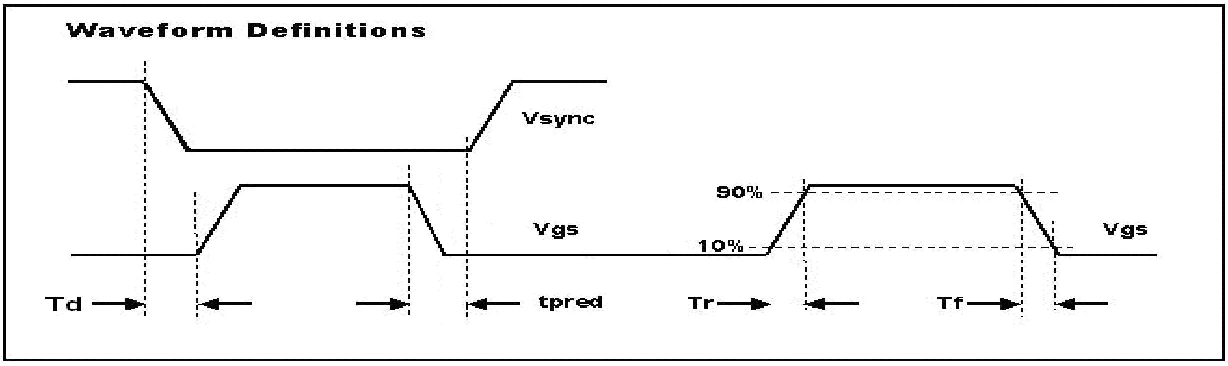


Figure 4: $t_{DEAD\ 2}$ vs Temperature (℃)

(*) Tr & Tf are measured among 10% and 90% of starting and final voltage.



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